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Wavelength dependent nonlinear optical response of tetraphenylethene aggregation-induced emission luminogens†

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Since the discovery of the striking aggregation-induced emission (AIE) phenomenon, tremendous efforts have been devoted to the exploration of brilliant organic solid-state light emitting materials and their underlying mechanistic theories. While AIE is well established in linear optics, the nonlinear optical (NLO) properties of the AIE luminogens (AIEgens) remain relatively unexplored. Here, we present a detailed study of the NLO properties of crystalline prototypical AIEgens based on tetraphenylethene (TPE). The results disclose a highly efficient NLO response of TPE crystals which is strongly dependent on the wavelength of the incident near infrared (NIR) light. TPE exhibits mainly two-photon excited fluorescence (TPF) upon excitation at $700\text{ nm} < \lambda < 800\text{ nm}$, while it exhibits three-photon excited fluorescence (3PF) if pumped at $800\text{ nm} < \lambda < 840\text{ nm}$. For pump wavelengths longer than 840 nm , mainly second harmonic generation (SHG) is observed. The introduction of halogen atoms into the TPE backbone results in comparable NLO hyperpolarizabilities, but allows for future derivations and functionalizations. The exploration of the nonlinear optical properties of AIEgens might open a new avenue to a next generation of multifunctional organic and composite photonic materials and devices.

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Introduction

The discovery of the exquisite aggregation induced emission (AIE) phenomenon^{1,2} has triggered an intense activity in the area of brilliant organic solid state light emitting materials.^{3–5} Substantial AIE luminogens (AIEgens) have been rationally designed, synthesized^{6–12} and widely applied in such diverse fields as organic light-emitting diodes (OLEDs),¹³ chemical/biological sensing,¹⁴ lasing,¹⁵ bioimaging,¹⁶ *etc.* However, most of the work on the established AIEgens is focused on their linear optical properties.¹⁷ In contrast, the nonlinear optical (NLO) properties of the AIEgens have attracted less attention,

although light emitting materials with high NLO coefficients are of crucial importance for a wide range of applications in modern technologies, ranging from light frequency conversion,¹⁸ optical telecommunications,¹⁹ information processing,²⁰ to data storage.²¹ Only a number of AIEgens have been demonstrated to exhibit NLO properties. Tang, He *et al.* studied higher-order NLO effects from a 2,3-bis(4-(phenyl(4-(1,2,2-triphenylvinyl)phenyl)-amino)phenyl)fumaronitrile (TTF) AIEgen,²² which found applications in up-conversion near-infrared (NIR) bioimaging.²³ However, most of these AIEgens are active in odd-order NLO effects.^{24,25} For highly efficient even-order NLO such as second harmonic generation (SHG), a strict non-centrosymmetric molecular arrangement in the aggregation state is required.^{26–28} SHG is a frequency-doubling process in which two incident photons combined to generate one photon with doubled frequency and energy.²⁶ The exploration of NLO properties based on the typical AIE molecules may broaden the applications of AIE material. We have recently reported a hexaphenylene based AIEgen, 4-DBpFO, showing second-order nonlinear optical two photon excited fluorescence (TPF) along with second-order nonlinear optical SHG.²⁹ However, the emission enhancement factor α_{AIE} (< 10) and the quantum yield Φ ($\sim 36\%$) of 4-DBpFO are relatively low, which might limit its practical applications.

Tetraphenylethene (TPE) is a prototypical AIEgen with a very high emission enhancement factor and a virtually unity

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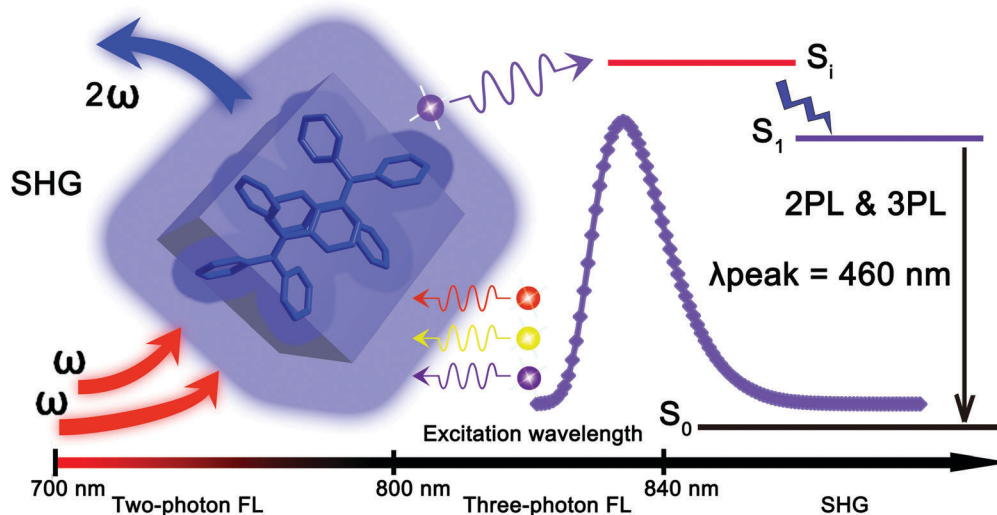
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Scheme 1 Schematic representation of the wavelength-dependent NLO properties of TPE.

quantum yield in the solid state.³⁰ The ease of its synthesis also offers diverse opportunities for molecularly engineered analogues with broad potential applications. It is also worth noting that TPE crystallizes in a P_{21} space group,^{3,4,31,32} which is intrinsically polar and non-centrosymmetric. Such a non-centrosymmetric molecular arrangement might endow the TPE materials with highly efficient even-order NLO effects. So far, the NLO properties of model TPE AIEgens have not been explored yet. In this work, we studied in detail the NLO properties of TPE AIEgen and found that its microcrystals exhibit very different NLO effects when pumped with femto-second (fs) laser pulses at different wavelengths. As shown in Scheme 1, the TPE crystal exhibits two-photon fluorescence, three-photon fluorescence and SHG when pumped with different incident beams of varied wavelengths. Importantly, the NLO signals of TPE show distinct wavelength dependent features. To be specific, when the pumped beam wavelength is larger than 840 nm, mainly SHG is observed. 3PL (three-photon luminescence) emission is observed for incident wavelengths between 800 nm and 840 nm, while only TPF is observed when the incident beam wavelength is shorter than 800 nm.

Furthermore, comparable SHG coefficient with modified AIEgen building blocks were obtained by introducing Br and I halogen atoms to the TPE backbone. The halogenation of TPE with Br and I introduces new conjugated donor–acceptor and intramolecular charge transfer (ICT)^{33–35} effects may cause different transition dipole moment compared to TPE, the induced halogen–halogen effects together with the C–H $\cdots\pi$ interactions driving the crystalline system from monoclinic to orthogonal. In addition, the halogen active sites on TPE present possibilities for further design and modifications to obtain novel NLO AIEgens. We believe that the discovery of nonlinear optical (NLO) properties of these classic AIEgens may open a broad research area to explore new organic NLO materials and applications.

Results and discussion

Wavelength dependent NLO properties of TPE microcrystals

High-quality bulk single crystals of TPE were readily grown by slowly evaporating its saturated solution in a mixed solvent of THF and *n*-hexane (v/v, 1:1) at room temperature. The single-crystal X-ray diffraction (SXRD) analysis suggests that the X-shaped TPE molecules are organized in a non-centrosymmetric orthorhombic P_{21} space group (point group: 2) (Table S1, ESI[†]), in line with the structure reported in literature.³² Every unit cell contains two smallest asymmetrical TPE molecules, of which the four side phenyl planes are twisted from the central olefin by $\theta_1 = 45.6^\circ$, $\theta_2 = 55.0^\circ$, $\theta_3 = 46.5^\circ$ and $\theta_4 = 48.5^\circ$, respectively (Fig. 1a and b). These twists induce side C–H \cdots C contacts, driving the formation of molecular chains along the crystallographic *b*-axis, which are further linked into a three dimensional (3D) space structure by supramolecular interactions (Fig. S9a, ESI[†]). The non-centrosymmetric nature of the TPE crystal endows its potential NLO properties. Indeed, the NLO spectra of TPE crystals exhibit strong SHG and multiple photon excitation fluorescence (Fig. 1c) upon fs laser excitations at different wavelengths. When the excitation wavelength is between 840 nm and 970 nm, SHG signals with sharp peaks in the spectra are observed at half the wavelength of the corresponding incident light. However, when the excitation wavelength is lower than 840 nm, a broad band emission centered around 460 nm appears in the spectra. Such a broad emission band is apparently an NLO process, considering its up-conversion characteristic from the NIR light to the visible range. Detailed power dependence measurements revealed the mechanism of these NLO processes (Fig. 1d). When the excitation beam wavelength is shorter than 800 nm (TPF) or greater than 840 nm (SHG), the slope of the power dependence of the intensity of the generated light is around 2.0, corroborating the two photon character of both processes. In contrast, a three-photon excitation character is observed with a slope around 3.0 for excitation wavelengths between 800 nm to 840 nm.^{36,37} The origin of the

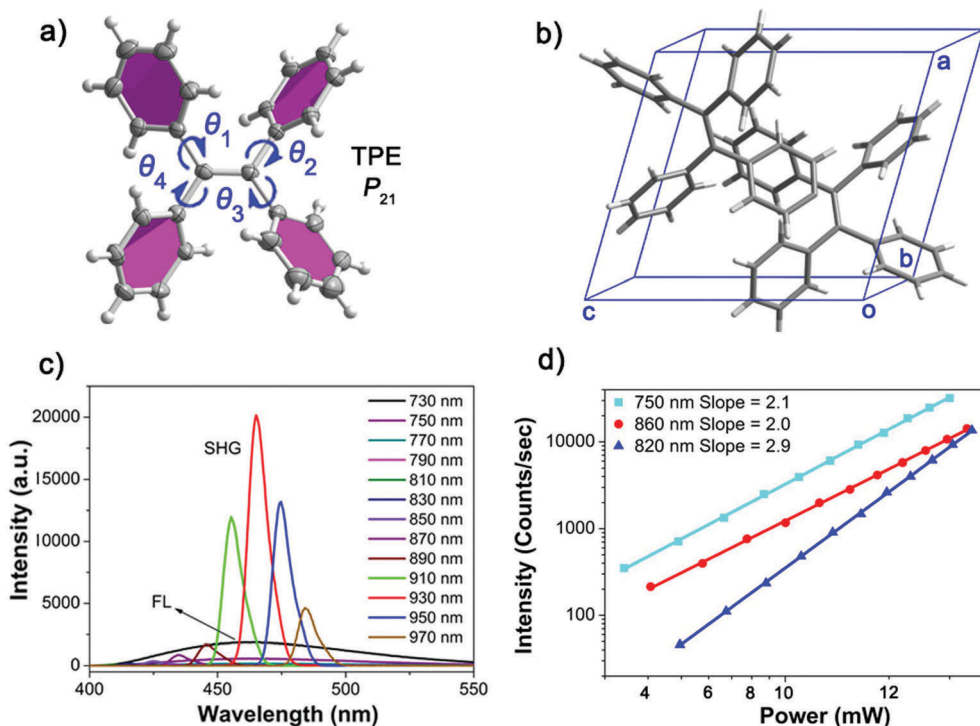


Fig. 1 (a) Molecular structure and torsion angles of TPE. (b) The unit cell structure of TPE. (c) The NLO spectra from a single TPE microcrystal pumped at different wavelengths ranging from 730 to 970 nm, with an interval of 20 nm, normalized by the square of the power of the pump at each wavelength. The broad peak centered at 460 nm is attributed to the two or three photon excited fluorescence, while the sharp peaks are from SHG. (d) Logarithmic plots of the power dependence of the generated NLO responses from the TPE microcrystal.

observed wavelength dependent phenomena can be attributed to the matching between the photon energy and the excitation energy threshold. That is, when exciting the TPE substrate with short wavelength light of substantial energy up to the energy gap between ground and excited state, the NLO process displays multi-photon fluorescence.²² In contrast, the NLO process shows an SHG signal when excited by long wavelength light with lower energy. Considering TPE is a prototype AIE molecule, the discovery of the wavelength dependent NLO properties may initiate a new way to explore NLO organic materials based on TPE AIEgens.

Crystal structures and morphologies of halogenated TPEs

Halogenation was performed on the initial TPE molecule.^{38,39} Both the resulting 4Br-TPE and 4I-TPE were found to crystallize in a non-centrosymmetric space group, while the formation of a non-centrosymmetric 4Cl-TPE supramolecular assembly failed. High quality crystals of 4Br-TPE and 4I-TPE suitable for single crystal XRD analysis were prepared by direct solvent evaporation of its solution in mixed THF and *n*-hexane. Very slow solvent evaporation resulted in large crystals with lengths in the centimeter scale (Fig. S4, ESI†). The introduction of halogen atoms causes halogen-halogen interactions,^{40,41} which, in combination with the C-H $\cdots\pi$ interactions, drive the non-centrosymmetric crystallization of 4Br-TPE and 4I-TPE with the orthorhombic $P2_12_12_1$ space group (point group: 222) (Table S1, ESI†). Single crystal XRD analysis shows that each asymmetric

unit contains four 4X-TPE (X = Br, I) molecules (Fig. S10, ESI†). The twist angles between the four outstretched phenyl planes and the central olefin are $\theta_1 = 50.7^\circ$, $\theta_2 = 46.6^\circ$, $\theta_3 = 57.4^\circ$ and $\theta_4 = 51.2^\circ$ for 4Br-TPE, and $\theta_1 = 51.2^\circ$, $\theta_2 = 53.7^\circ$, $\theta_3 = 50.6^\circ$ and $\theta_4 = 49.0^\circ$ for 4I-TPE. These twists can facilitate the C-H $\cdots\pi$ interactions. Double-chain structures of 4Br-TPE along the crystallographic *a*-axis are connected *via* these C-H $\cdots\pi$ interactions with distances of 3.1 Å. The synergistical Br \cdots Br interactions with distances of 4.0 Å is also found to stabilize the molecular chains along the *a*-axis. For 4I-TPE, similar double-chain structures along the *a*-axis are present with C-H $\cdots\pi$ distance (3.1 Å and 3.4 Å), while a molecular chain connected by I \cdots I interactions (3.9 Å) is along the *b*-axis (Fig. S9, ESI†). These multiple intermolecular interactions contribute to the molecular assembly and extend over the whole crystals. Furthermore, the simulation results on the morphologies of 4Br-TPE and 4I-TPE crystals agreed very well with the observed molecular and supramolecular self-assembled structures, confirming that the crystallographic *a*-axis ([001] direction) is the long axis of the microrods of both 4Br-TPE and 4I-TPE (Fig. 5).

It is important to clarify the relationship between the observed NLO signals and the supramolecular assembly from single molecules to microstructure architectures. Therefore, a clear and neat crystal morphology is necessary.³⁷ The re-precipitation method was used to cultivate the micro-sized crystals of TPE and its derivatives in different morphologies and sizes. When the TPE micro crystal had a morphology of a diamond

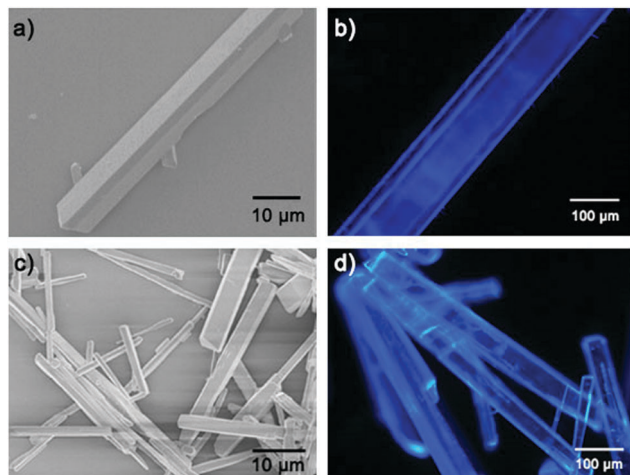


Fig. 2 Morphologies of 4Br-TPE and 4I-TPE microcrystals. (a) SEM image of microrod 4Br-TPE; (b) fluorescent microscopic image of 4Br-TPE; (c) SEM image of 4I-TPE microrod; (d) fluorescent microscopic image of 4I-TPE.

polyhedron (Fig. S1, ESI[†]), nice rod-like microcrystals of both 4Br-TPE and 4I-TPE have been grown by the re-precipitation method under the same conditions (Fig. 2). The well-defined 1D structure of these microcrystals paved the way for further elaborating the polarization-dependence of the NLO responses, allowing for the exploration of the relationships between the

structure and the NLO properties. In a typical procedure, injecting a concentrated solution of 4Br-TPE or 4I-TPE in the effective solvent THF (5 mg mL⁻¹, 200 μ L) into the ineffective solvent *n*-hexane (5 mL) under vigorous stirring produces micro-sized rod-like crystals with widths of a few micrometers and lengths of tens of micrometers. Fluorescence microscope images (Fig. 2b and d) suggest that the microstructures of 4Br-TPE and 4I-TPE are both intense blue emitters under UV (330–380 nm) light excitation. Powder XRD patterns of the three compounds fitted well with their single-crystal XRD respectively, which further proved the crystal phase purity (Fig. S2, ESI[†]). The TG analysis (Fig. S3, ESI[†]) reveals that the halogenation significantly strengthens the stability of the TPE derivatives.

Linear optical properties

Emission spectrum of 4Br-TPE and 4I-TPE in solvents of diverse H₂O/tetrahydrofuran (THF) gradients distinctively exhibit the AIE phenomenon (Fig. S5 and S6, ESI[†]). The fluorescence intensity of both 4Br-TPE and 4I-TPE enhanced as the water fraction (f_w) increased gradually.⁴² The fluorescence intensity in absolute H₂O were enhanced by nearly 14 and 15 times for 4Br-TPE and 4I-TPE in THF, respectively. Both the emission maximum of 4Br-TPE and 4I-TPE in the mixed solvents reveal a bathochromic shift tendency with the f_w increased from 0% to 90%, and then hypsochromic shift to nearly the same as that of crystal states finally. This might be caused by the morphology

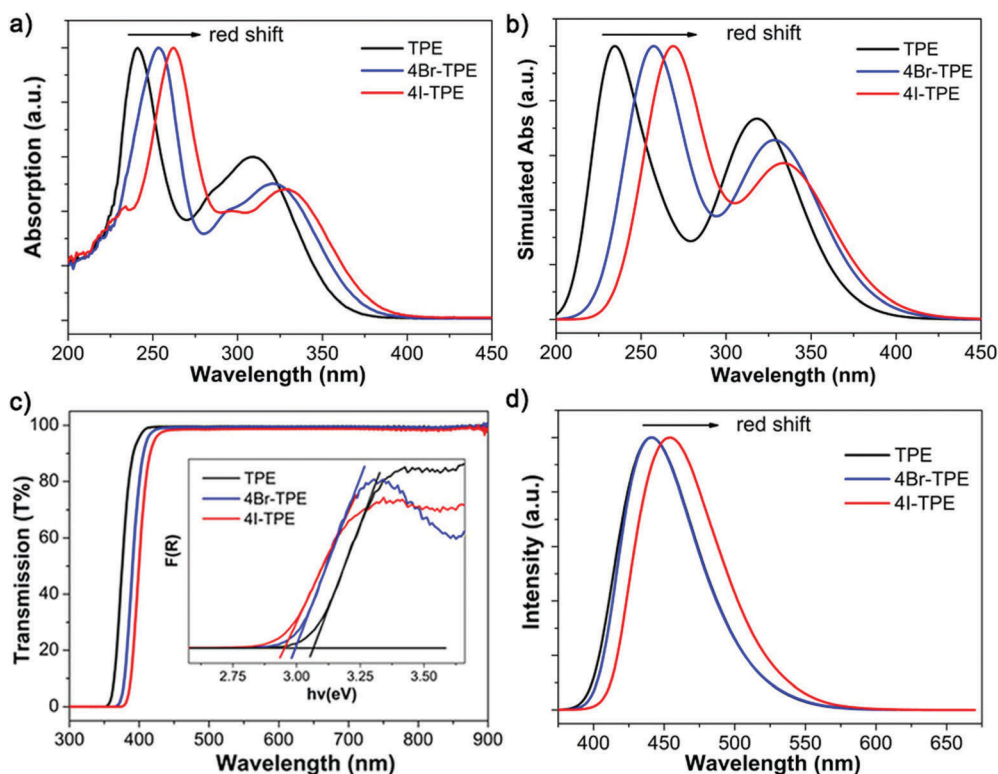


Fig. 3 Linear optical properties of 4Br-TPE and 4I-TPE, in comparison with those of TPE. (a) Normalized absorption spectra of TPE, 4Br-TPE and 4I-TPE in THF solution. (b) Simulated absorption spectra of TPE, 4Br-TPE and 4I-TPE in THF solution. (c) Transmission spectra of TPE, 4Br-TPE and 4I-TPE (1×10^{-3} M, 1 cm thickness). The inset shows the calculated band gaps of TPE, 4Br-TPE and 4I-TPE crystals based on the $(xh\nu)^2-h\nu$ curves (TPE: $E_g = 3.06$ eV; 4Br-TPE: $E_g = 3.00$ eV; 4I-TPE: $E_g = 2.95$ eV). (d) Normalized photoluminescence spectra of crystallized TPE, 4Br-TPE and 4I-TPE.

change of the aggregates.³¹ The AIE nature of 4Br-TPE and 4I-TPE can be further prove by the temperature-dependent photoluminescence. As shown in Fig. S6 (ESI[†]), the emission intensity in liquid nitrogen temperature (77 K) of 4Br-TPE and 4I-TPE enhanced 4.6 and 6.6 times compared to that in the room temperature (298 K), respectively. That means the energy dissipation process is blocked at extremely low temperature.¹⁰ The linear optical properties of TPE, 4Br-TPE and 4I-TPE are shown in Fig. 3. The solid state photoluminescence (PL) spectra of TPE and 4Br-TPE exhibit emission bands both peaking at 440 nm. The emission spectra of TPE coincide with the previously reported results^{3,4} and the PL spectra of 4Br-TPE shows a tiny red shift compared to that of TPE (~ 5 nm). While the PL spectrum of 4I-TPE exhibits a distinct red shift (14 nm) with the emission peak centered at 454 nm (Fig. 3d). The crystal state absolute quantum yields (Φ) of 4Br-TPE and 4I-TPE were measured to be 30.07% and 15.49%, respectively (Fig. S7 and S8, ESI[†]). The reduction of quantum yield of 4I-TPE compared to 4Br-TPE may induced by the heavy atom effect of iodine.⁴³ The UV/vis diffuse reflectance spectra indicate that TPE and its halogenated derivatives have a wide transparent region with the absorption edges of 352, 366 to 375 nm for TPE, 4Br-TPE and 4I-TPE, respectively (Fig. 3c).⁴³ The measured absorption spectra of TPE, 4Br-TPE and 4I-TPE in THF display a red shift trend both on the primary band (visible region) and subordinated band (UV region) (Fig. 3a). Besides, the simulated absorption spectra exhibit the same red-shift tendency, in good agreement with the experimental results with slight difference less than 10 nm (Fig. 3b). The red-shift of the linear optical emission from TPE to 4I-TPE might be attributed to the heavy atom effect of the halogens. Specially, the excitations of the heavy halogen atoms have high

possibilities to undergo intersystem crossing transitions thus causing power reduction of the radiation.⁴⁴ The band gaps as calculated from the crystal state absorption spectra also display a decreasing trend with values of 3.06, 3.00 and 2.95 eV (Fig. 3c, inset).

In order to clarify the structure-property correlations, theoretical calculations of both the molecular and supramolecular structures were performed. Electronic structures of the three compounds show distinct charge-transfer characteristics between the highest occupied molecular orbitals (HOMOs) and the lowest unoccupied molecular orbitals (LUMOs) with band gaps of 2.96 eV, 2.81 eV and 2.73 eV for single molecules of TPE, 4Br-TPE and 4I-TPE, respectively (Fig. 4a). These values calculated based on crystal structures are 2.86 eV, 2.71 eV and 2.58 eV. The calculation results from both single molecules and aggregated crystal structures are nearly the same and accorded well with the bandgap values fitted from UV-vis absorption spectrum.^{45,46} The single molecule transition dipoles of the three compounds are calculated to be 4.88 D, 5.52 D, and 6.03 D for TPE, 4Br-TPE, and 4I-TPE, respectively (Fig. 4), and oriented vertical to the central olefin direction (Fig. S10 and S11, ESI[†]). In contrast, the direction of the overall transition dipole of both 4Br-TPE and 4I-TPE is about 45° offset from the long axis of the microrods ([001]; Fig. 5c and d).

NLO properties of 4Br-TPE and 4I-TPE

The discovery of the wavelength-dependent NLO responses from TPE ignited our interest to further study the NLO properties of the

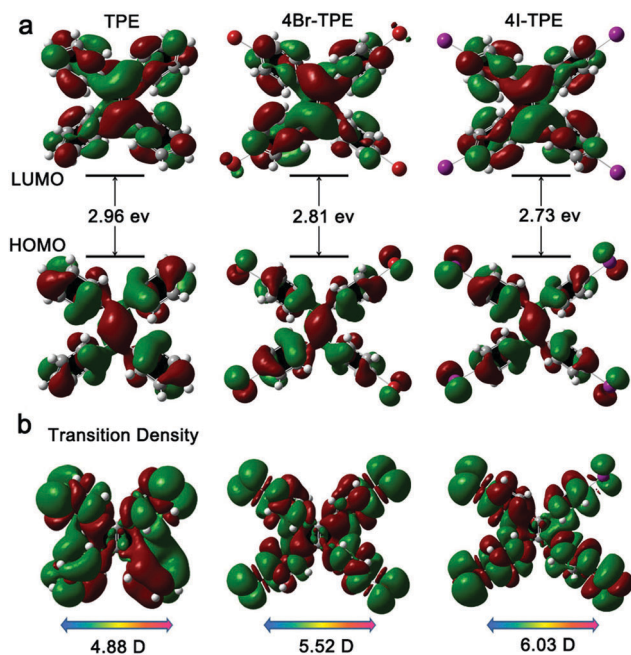


Fig. 4 (a) Calculated electronic structures and bandgaps of TPE, 4Br-TPE and 4I-TPE; (b) the transition densities corresponding to $S_0 \rightarrow S_1$ of TPE, 4Br-TPE and 4I-TPE.

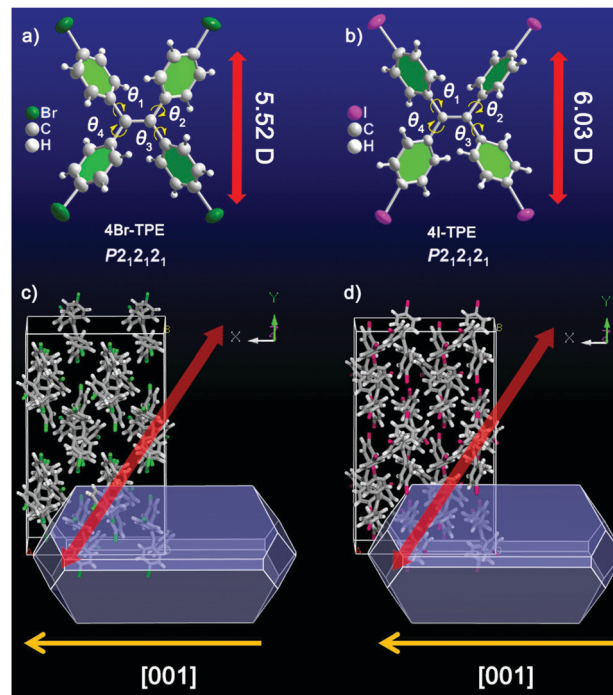


Fig. 5 Asymmetric molecular arrangement showing the torsion angles between the outstretched phenyl planes and central olefin of 4Br-TPE (a) and 4I-TPE (b). The simulated morphology and supramolecular packing of 4Br-TPE (c) and 4I-TPE (d), the inserted yellow arrows indicate the directions of the axis of the microrods, while the red arrows show the orientations of the overall transition dipole.

halogenated TPE AIEgens (4Br-TPE and 4I-TPE) as they both crystallize in a non-centrosymmetric $P2_12_12_1$ space group. As shown in Fig. 6a and b, the wavelength dependent NLO spectra vividly exhibit the frequency-doubling effect with the SHG peaks appearing at half the wavelength of the femtosecond excitation beam. The SHG signal of 4Br-TPE can be tuned from 400 to 480 nm when the excitation beam was varied from 800 to 960 nm, while the corresponding signals of 4I-TPE are tuned from 390 to 490 nm with the excitation from 780 to 980 nm. The TPF peak of 4I-TPE (470 nm) shows a red shift of ~ 10 nm compared to that of 4Br-TPE (460 nm), which is mainly attributed to the heavy halogen atom effect of the iodine.^{47,48} It deserves

to notice that for the crystal state of TPE, 4Br-TPE, and 4I-TPE, the peak position of TPF is red-shifted from their one-photon fluorescence, that is probably due to the reabsorption effect.⁴⁹ Similarly, the NLO emission of 4Br-TPE and 4I-TPE also possesses wavelength dependent properties with mainly SHG signal when the wavelength of the excitation beam is longer than 800 nm. TPF emission is observed when the excitation wavelength is between 740 and 800 nm. The two-photon nature of the two NLO process is further demonstrated by the slope fitting of the relation between the NLO intensity and the pump laser power, which indicates a quadratic dependence (Fig. 6c and d).⁵⁰

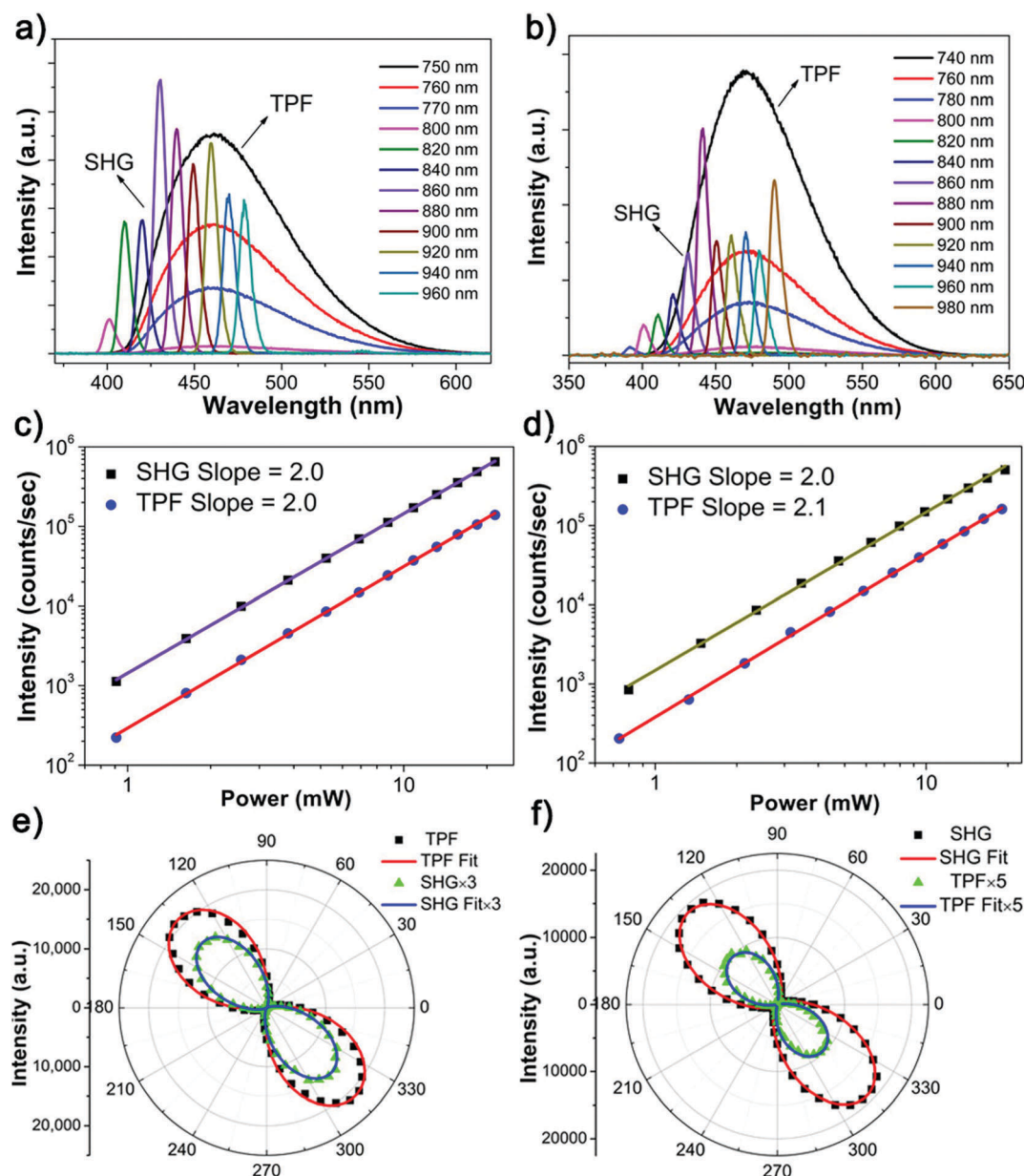


Fig. 6 Nonlinear optical properties of 4Br-TPE (a, c and e) and 4I-TPE (b, d and f). The wavelength dependent NLO spectrum of 4Br-TPE (a) and 4I-TPE (b) pumped at different wavelengths ranging from 740 to 980 nm, with an interval of 20 nm, normalized by the square of the input laser power. The logarithmic fitting plot of the power dependence of SHG and TPF from 4Br-TPE (c) and 4I-TPE (d). Anisotropic SHG and TPF polarization dependent plots of 4Br-TPE (e) and 4I-TPE (f), the red and blue lines indicate the $\cos^4 \theta$ and $\cos^2 \theta$ fits for SHG and TPF, respectively.

The NLO responses from both the 4Br-TPE and 4I-TPE microrods were studied as function of the polarization of the incident light in order to clarify the anisotropic effects of the NLO signals.⁵¹ The microrod objects were aligned vertical to the plane of the polarized beam, and the polarization angle was tuned from 0° to 180°. As shown in Fig. 6e and f, both the SHG signal and TPF emission of 4Br-TPE and 4I-TPE have a similar polarization dependence trend. They both reach maxima when the polarization angle is near 135° or 315°, which is about 45° incline to the vertically aligned rodshaped crystal. The simulations suggest that the orientations of the S_0-S_1 transition dipoles of both 4Br-TPE and 4I-TPE are about 45° deviated from the crystal long axis of the [001] direction, in good agreement with the measured polarization dependence. The polarization ratio of SHG, $\rho = (I_{\max} - I_{\min}) / (I_{\max} + I_{\min})$, is 0.99 ± 0.01 and 0.92 ± 0.04 for 4Br-TPE and 4I-TPE, while the polarization ratio of TPF is 0.95 ± 0.04 and 0.99 ± 0.01 for 4Br-TPE and 4I-TPE, respectively. The SHG polarization ratio here is almost equally to that of DPFO (2,7-diphenyl-9H-fluoren-9-one), a typical NLO organic microfiber, while the TPF polarization ratio of halogenated TPE here are distinctly larger than that of DPFO.²⁹ It is worth noting that the polarization ratios are practically one, which is higher than for the overwhelming majority of the reported organic crystals^{26,39,52} and even higher than some inorganic NLO materials.⁵³ The TPF polarization ratio is more concerned to the transition dipole while the SHG polarization is mainly affected by permanent dipole moment, the bromine atoms contribute more to the permanent dipole moment, thus the 4I-TPE got the higher TPF polarization ratio and lower SHG polarization ratio compared to 4Br-TPE. The high polarization ratio values may be induced by the intramolecular charge transfer (ICT)^{33,48} between the aromatic benzenes and halogens, as well as the S_0-S_1 transition dipoles.⁵⁴ The very high ρ value and the nice agreement between the transition dipole simulations and the polarization dependent experiments further showed that the well-oriented transition dipole moment plays a vital role in the design of supramolecular AIE NLO materials.

Conclusions

The NLO response of the prototype AIEgen tetraphenylethylene (TPE) demonstrates various NLO properties, including SHG, TPF and 3PL depending on the wavelength of the excitation beam. Simple halogenation modification of the TPE AIEgen results in well-defined microrods of 4Br-TPE and 4I-TPE and comparable SHG signals with very high polarization ratios. Theoretical calculations together with polarization-dependent experiments show that the transition dipole moment is one of the key parameter for the design of NLO AIEgen materials with large hyperpolarizabilities. We believe this work may open a new area for the exploration of NLO materials based on AIEgens.

Experimental

Reagents and materials

All reagents were commercially purchased and used without further purification. Powder X-ray diffraction (PXRD) patterns

were collected with Cu K α radiation ($\lambda = 1.54178 \text{ \AA}$). Above-room-temperature thermo gravimetric analysis (TGA) measurements were made using a TA Instruments STD 2960 from 293 to 1000 K. Steady fluorescence spectra were collected on a Hitachi F-7000 fluorescence spectrophotometer. UV-VIS spectra and transmission spectra were recorded using a PERSEE TU-1950 UV-VIS spectrophotometer. The microcrystal morphology was characterized by SEM (FE-SEM, JSM-7800). Fluorescence images were obtained using an automated Leica DM5000B microscope equipped with a 340–380 nm band pass excitation filter cube. NLO examinations were performed using a home-built set-up.³⁷ The calculations were conducted in Gaussian09 (Revision D.01) with Perdew–Burke–Ernzerhof (PBE) density function.⁵⁵ The basis sets were employed lanl2dz with pseudo potentials for Br and I, and 6-31G(d) for other elements. The k -points for Brillouin zone were automatically selected as $4 \times 4 \times 4$ for TPE and $4 \times 4 \times 2$ for TPE-Br and TPE-I, respectively. The energy band gap of the crystals was represented by the minimal direct gap. The predicted crystal morphologies were simulated by materials studio 8.0.

Single-crystal X-ray crystallography

Single-crystal X-ray diffraction data were collected on a Super-Nova diffractometer with graphite-monochromated Cu K α radiation ($\lambda = 1.54184 \text{ \AA}$). The structures were solved with direct methods using the SHELXTL program⁵⁶ and refined with full-matrix least squares on F^2 .⁵⁷ The corresponding Cambridge Crystallographic Data Centre (CCDC) reference number of TPE, 4Br-TPE and 4I-TPE are 1837773, 1837774 and 1837775, respectively.†

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

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